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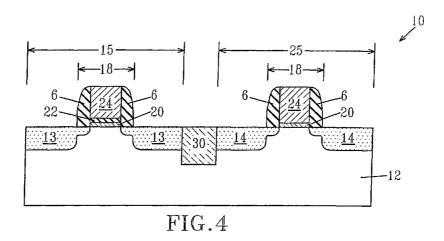
- (71) Applicant (for all designated States except US): INTERNATIONAL BUSINESS MACHINES CORPORATION [US/US]; New Orchard Road, Armonk, NY 10504 (US).
- (72) Inventors; and
- (75) Inventors/Applicants (for US only): BOJARCZUK, Nestor A., Jr. [US/US]; 61 David Drive, Poughkeepsie, NY 12601 (US). CABRAL, Cyril, Jr. [US/US]; 17 Goldfinch Lane, Mahopac, NY 10541 (US). CARTIER, Eduard A. [CH/US]; 101 West 85th Street, Apt. # 6-6, New York, NY 10024 (US). COPEL, Matthew W. [US/US]; 2570 Barry Court, Yorktown Heights, NY 10598 (US). FRANK, Martin M. [DE/US]; 310 West

77th Street, New York, NY 10024 (US). GOUSEV, Evgeni P. [RU/US]; 10 Raven Road, Mahopac, NY 10541 (US). GUHA, Supratik [US/US]; 569 Millwood Road, Chappaqua, NY 10514 (US). JAMMY, Rajarao [IN/US]; 14 Traci Lane, Hopewell Junction, NY 12533 (US). NARAYANAN, Vijay [IN/US]; 180 Riverside Boulevard, Apt. # 12C, New York, NY 10069 (US). PARUCHURI, Vamsi K. [IN/US]; 505 Columbus Avenue, Apt. # 4E, New York, NY 10024 (US).

- (74) Agent: GROLZ, Edward W.; Scully, Scott, Murphy & Presser, 400 Garden City Plaza, Garden City, NY 11530 (US).
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(54) Title: SELECTIVE IMPLEMENTATION OF BARRIER LAYERS TO ACHIEVE THRESHOLD VOLTAGE CONTROL IN CMOS DEVICE FABRICATION WITH HIGH K DIELECTRICS



(57) Abstract: A method of forming a CMOS structure, and the device produced therefrom, having improved threshold voltage and flatband voltage stability. The inventive method includes the steps of providing a semiconductor substrate having an nFET region and a pFET region; forming a dielectric stack atop the semiconductor substrate comprisisng an insulating interlayer atop a high k dielectric; removing the insulating interlayer from the nFET region without removing the insulating interlayer from the pFET region; and providing at least one gate stack in the pFET region and at least one gate stack in the nFET region. The insulating interlayer can be A1N or A1OxN $_Y$ . The high k dielectric can be HfO $_2$ , hafnium silicate or hafnium silicon oxynitride. The insulating interlayer can be removed from the nFET region by a wet etch including a HC1/H $_2$ O $_2$  peroxide solution.



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ZW), Eurasian (AM, AZ, BY, KG, KZ, MD, RU, TJ, TM), European (AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IS, IT, LT, LU, MC, NL, PL, PT, RO, SE, SI, SK, TR), OAPI (BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG).

#### **Declarations under Rule 4.17:**

— as to applicant's entitlement to apply for and be granted a patent (Rule 4.17(ii))

— as to the applicant's entitlement to claim the priority of the earlier application (Rule 4.17(iii))

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#### INTERNATIONAL SEARCH REPORT

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PCT/US05/10825

A. CLASSIFICATION OF SUBJECT MATTER  IPC: H01L 29/792(2006.01)						
n C. Hote 29/192( 2000.01)						
USPC: 257/324,369,411 According to International Patent Classification (IPC) or to both national classification and IPC						
B. FIELD	OS SEARCHED					
	cumentation searched (classification system followed b	w classifica	tion symbols)			
U.S.: 257/324,369,411						
Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched						
Electronic data base consulted during the international search (name of data base and, where practicable, search terms used)						
C. DOCUMENTS CONSIDERED TO BE RELEVANT						
Category *	Citation of document, with indication, where a	ppropriate,	of the relevant passages	Relevant to claim No.		
Y	US 6,538,278 B1 to Chau, 25 March 2003 (25.03.20	03), Fig. 2,	col. 3 line 6-col. 5 line 34.	1-27		
	US 6,407,435 B1 to Ma et al., 18 June 2002 (18.06.2	002), Figs.	2-3, col. 2, lines 4-8.			
}						
1						
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	documents are listed in the continuation of Box C.		See patent family annex.			
Sp	necial categories of cited documents:	"T"	later document published after the inter date and not in conflict with the applica			
"A" document o	defining the general state of the art which is not considered to be of		principle or theory underlying the inven	tion		
		"X"	document of particular relevance; the cl			
"E" earlier appl	lication or patent published on or after the international filing date		considered novel or cannot be consider when the document is taken alone	ed to involve an inventive step		
	which may throw doubts on priority claim(s) or which is cited to the publication date of another citation or other special reason (as	"Y"	document of particular relevance; the cl considered to involve an inventive step			
"O" document i	referring to an oral disclosure, use, exhibition or other means		with one or more other such documents obvious to a person skilled in the art	, such combination being		
	published prior to the international filing date but later than the	"&"	document member of the same patent fa	amily		
priority dat		œ	nocument themsel of the same patent is	шиу		
Date of the actual completion of the international search			nailing of the international searc	h report		
17 March 2008 (17.03.2008)		ZIMAR ZUUU				
Name and mailing address of the ISA/US		Authorized officer				
Mail Stop PCT, Attn: ISA/US Commissioner for Patents		Andy Huynh & You Slub Far				
P.O. Box 1450		Telephone No. 571-272-1781				
Alexandria, Virginia 22313-1450 Facsimile No. (571) 273-3201			C 190. 3/1-2/2-1/81			
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Form PCT/ISA/210 (second sheet) (April 2007)

### INTERNATIONAL SEARCH REPORT

International application No.
PCT/US05/10825

Box No. II	Observations where certain claims were found unsearchable (Continuation of item 2 of first sheet)			
This internati	onal search report has not been established in respect of certain claims under Article 17(2)(a) for the following reasons:			
1.	Claims Nos.: because they relate to subject matter not required to be searched by this Authority, namely:			
2.	Claims Nos.: because they relate to parts of the international application that do not comply with the prescribed requirements to such an extent that no meaningful international search can be carried out, specifically:			
3.	Claims Nos.: because they are dependent claims and are not drafted in accordance with the second and third sentences of Rule 6.4(a).			
Box No. III Observations where unity of invention is lacking (Continuation of item 3 of first sheet)				
This Internati Please See Co	onal Searching Authority found multiple inventions in this international application, as follows: ontinuation Sheet			
1.	As all required additional search fees were timely paid by the applicant, this international search report covers all searchable claims.  As all searchable claims could be searched without effort justifying additional fees, this Authority did not invite payment of any additional fees.  As only some of the required additional search fees were timely paid by the applicant, this international search report covers only those claims for which fees were paid, specifically claims Nos.:			
4. Remark on F	No required additional search fees were timely paid by the applicant. Consequently, this international search report is restricted to the invention first mentioned in the claims; it is covered by claims Nos.: 1-27  The additional search fees were accompanied by the applicant's protest and, where applicable, the payment of a protest fee.  The additional search fees were accompanied by the applicant's protest but the applicable protest fee was not paid within the time limit specified in the invitation.  No protest accompanied the payment of additional search fees.			

Form PCT/ISA/210 (continuation of first sheet(2)) (April 2007)

	International application No.	
INTERNATIONAL SEARCH REPORT	PCT/US05/10825	
DOVIN ORGEDIVATIONS WHERE LIMITY OF INVENITION IS LACVE	NG.	
BOX III. OBSERVATIONS WHERE UNITY OF INVENTION IS LACKING.  I. Claims 1-27, drawn to a semiconductor device.	NO	
II. Claims 28-54, drawn to a process of making a semiconductor device.		
	DOT Dale 12.1 because and de DOT Dale	
The inventions listed as Groups I and II do not relate to a single general inventive co 13.2, they lack the same or corresponding special technical features for the following	g reasons: Inventions I and II are related as product	
made and process of making.		